

# Single Phase Rectifier Bridge

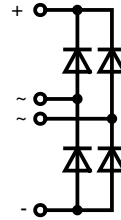
Standard and Avalanche Types

$$I_{dAV} = 31 \text{ A}$$

$$V_{RRM} = 800-1600 \text{ V}$$

$V_{RSM}$ V	$V_{BRmin}$ ① V	$V_{RRM}$ V	Standard Types	Avalanche Types
900		800	VBO 20-08NO2	
1300	1230	1200	VBO 20-12NO2	VBO 20-12AO2
1700	1630	1600	VBO 20-16NO2	VBO 20-16AO2

① For Avalanche Types only



Symbol	Conditions	Maximum Ratings
$I_{dAV}$ ②	$T_C = 85^\circ\text{C}$ , module	31 A
$I_{dAVM}$	module	40 A
$P_{RSM}$	$T_{VJ} = T_{VJM}$	3.4 kW
$I_{FSM}$	$T_{VJ} = 45^\circ\text{C}$ ; $t = 10 \text{ ms}$ (50 Hz)	300 A
	$V_R = 0$ ; $t = 8.3 \text{ ms}$ (60 Hz)	315 A
	$T_{VJ} = T_{VJM}$ ; $t = 10 \text{ ms}$ (50 Hz)	250 A
	$V_R = 0$ ; $t = 8.3 \text{ ms}$ (60 Hz)	265 A
$I^2t$	$T_{VJ} = 45^\circ\text{C}$ ; $t = 10 \text{ ms}$ (50 Hz)	450 A <sup>2</sup> s
	$V_R = 0$ ; $t = 8.3 \text{ ms}$ (60 Hz)	420 A <sup>2</sup> s
	$T_{VJ} = T_{VJM}$ ; $t = 10 \text{ ms}$ (50 Hz)	312 A <sup>2</sup> s
	$V_R = 0$ ; $t = 8.3 \text{ ms}$ (60 Hz)	290 A <sup>2</sup> s
$T_{VJ}$		-40...+150 °C
$T_{VJM}$		150 °C
$T_{stg}$		-40...+125 °C
$V_{ISOL}$	50/60 Hz, RMS $t = 1 \text{ min}$	3000 V~
	$I_{ISOL} \leq 1 \text{ mA}$ $t = 1 \text{ s}$	3600 V~
$M_d$	Mounting torque (M5) (10-32 UNF)	1.5-2 Nm
		13-18 lb.in.
<b>Weight</b>	Typ.	15 g

Symbol	Conditions	Characteristic Values
$I_R$	$V_R = V_{RRM}$ $T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = T_{VJM}$	0.3 mA
		5.0 mA
$V_F$	$I_F = 55 \text{ A}$ $T_{VJ} = 25^\circ\text{C}$	1.8 V
$V_{T0}$	For power-loss calculations only	0.85 V
$r_t$		14 mΩ
$R_{thJC}$	per diode; 120° el. per module	3.00 K/W
		0.75 K/W
$R_{thJH}$	per diode; 120° el. per module	3.40 K/W
		0.85 K/W
$d_S$	Creeping distance on surface	13 mm
$d_A$	Creepage distance in air ③	9.5 mm
$a$	Max. allowable acceleration	50 m/s <sup>2</sup>

Data according to IEC 60747 and refer to a single diode unless otherwise stated.

② for resistive load at bridge output

③ with isolated fast-on tabs.

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## Features

- Avalanche rated parts available
- Package with DCB ceramic base plate
- Isolation voltage 3600 V~
- Planar passivated chips
- Low forward voltage drop
- ¼" fast-on terminals
- UL registered E 72873

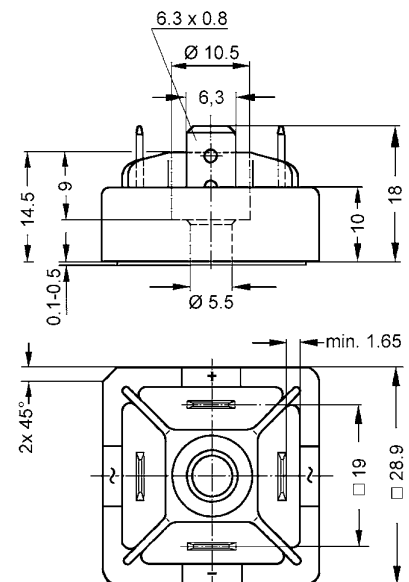
## Applications

- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

## Advantages

- Easy to mount with one screw
- Space and weight savings
- Improved temperature & power cycling

## Dimensions in mm (1 mm = 0.0394")



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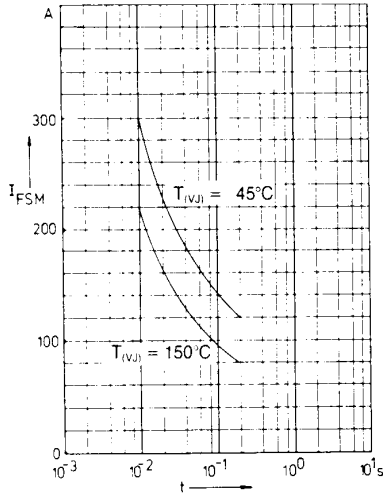


Fig. 1 Surge overload current per diode  
I<sub>FSM</sub>: Crest value, t: duration

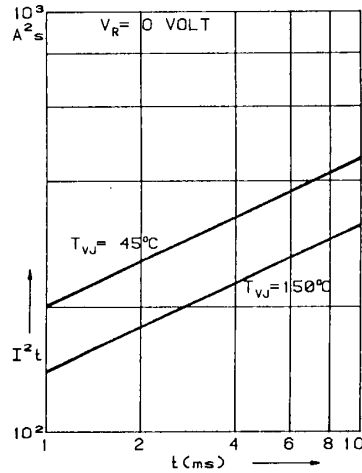


Fig. 2 I<sup>2</sup>t versus time (1-10 ms) per diode

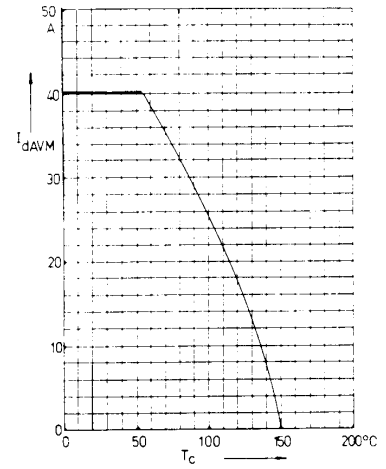


Fig. 3 Max. forward current at case temperature

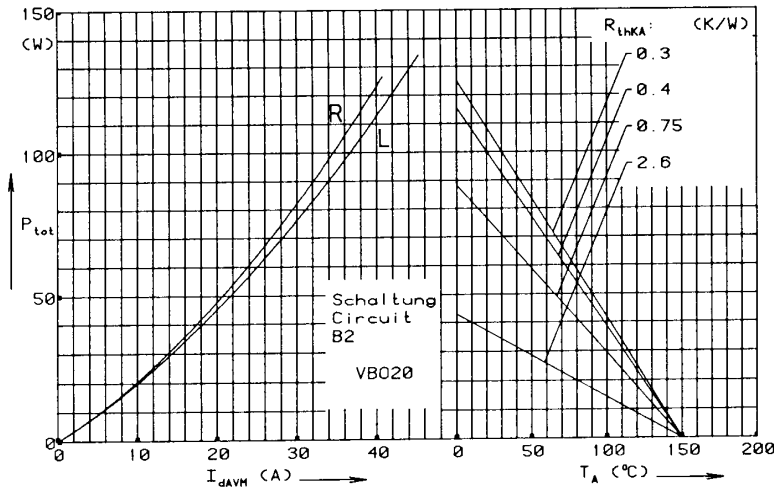


Fig. 4 Power dissipation versus direct output current and ambient temperature

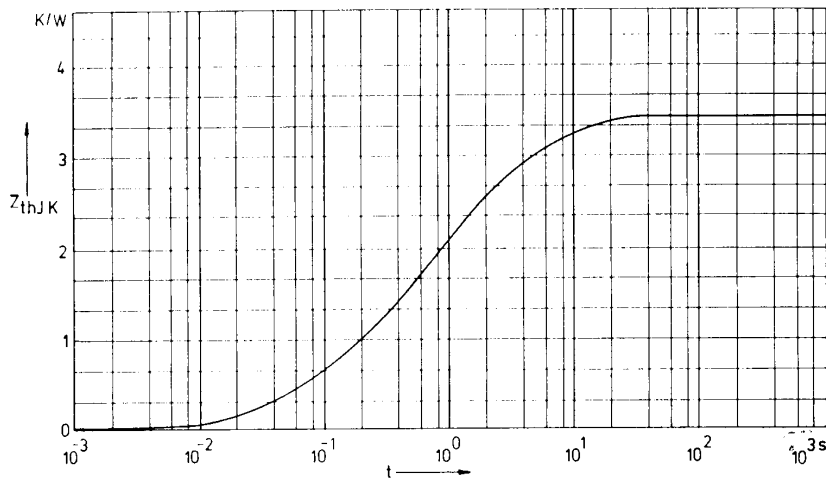


Fig. 5 Transient thermal impedance junction to heatsink per diode

Constants for Z<sub>thJK</sub> calculation:

i	R <sub>thi</sub> (K/W)	t <sub>i</sub> (s)
1	0.775	0.0788
2	1.390	0.504
3	1.255	3.701

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